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Implementing an LCD TV Power Supply with the NCP1396A, NCP1605, and NCP1027



Introduction

This document provides a detailed description of the implementation of an LCD TV power supply. The LDC TV supply unit exhibits high efficiency, low EMI noise and a low profile construction. The board contains DCM/CCM PFC front stage, 210 W LLC power stage and 12.5 W standby flyback converter.

The design requirements for our LCD TV power unit are as follows:

Requirement	Min	Мах	Unit
Input Voltage	90	265	Vac
Output Voltage 1	-	12	Vdc
Output Current 1	0	3	А
Output Voltage 2	-	24	Vdc
Output Current 2	0	6	А
Output Voltage 3	-	30	Vdc
Output Current 3	0	1	А
Output Voltage Standby Output	-	5	Vdc
Output Current Standby Output	0	2.5	А
Total Output Power	0	222.5	W
Total No Load Consumption for 0.5W Load on the Standby Output	-	1	W

NOTE: Only 24 V output is regulated in this version of the board. Additional output(s) regulation can be assured by adding feedback resistors to desired output (or outputs for percentage weight).

The NCP1396A resonant mode controller has been selected for this application because the soft-start absence on the fast fault input offers an easy implementation of the skip cycle mode. This helps to assure regulation of the resonant converter under no load conditions. The NCP1396A offers many other features that are advantageous for our application.

Brown-Out (BO) Protection Input

The input voltage of the resonant converter, when divided down, is permanently monitored by the Brownout pin. If the voltage on the bulk capacitor falls outside of the desired operating range, the controller drive output will be shut off. This feature is necessary for an LLC topology that uses PFC stage without PFC OK control output. In our case the BO input is used as an enabling input and is fully controlled by the front stage controller output (PFC OK).



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Timer Based Fault Protection

The converter stops operation after a programmed delay when the protection is activated. This protection can be implemented as a cumulative or integrating characteristic. Thus, under transient load conditions the converter output will not be turned off, unless the extreme load condition exceeds the timeout.

Common Collector Optocoupler Connection

The open collector output allows multiple inputs on the feedback pin i.e. over current sensing circuit, over temperature sensor, etc. The additional input can pull up the feedback voltage level and take over the voltage feedback loop.

600 V High Voltage Floating Driver

The high side driver features a traditional bootstrap circuitry, requiring an external high-voltage diode for the capacitor refueling path. The device incorporates an upper UVLO circuitry that guarantees enough V_{gs} is available for the upper side MOSFET.

Adjustable Dead-Time (DT)

Due to a single resistor wired between DT pin and ground, the user has the option to include needed dead- time, helping to fight cross- conduction between the upper and the lower transistor.

Adjustable Minimum and Maximum Frequency Excursion

Using a single external resistor, the designer can program its lowest frequency point, obtained in lack of feedback voltage (during the startup sequence or in short-circuit conditions). Internally trimmed capacitors offer a $\pm 3\%$ precision on the selection of the minimum switching frequency. The adjustable maximum frequency is less precise ($\pm 15\%$). Please refer to the NCP1396A/B data sheet for detailed description of all mentioned and additional features.

Detailed Demo Board Connection Description

A schematic of the proposed LCD TV power supply is shown in Figure 1. As already mentioned, the supply contains three blocks: a PFC front stage, an LLC converter and an auxiliary flyback converter that powers a TV set during standby and provides bias power for PFC and LLC control circuits during normal operation.



Figure 1. Schematic of the NCP1396A LCD TV Application

PFC Front Stage

The NCP1605 (IC₁) PFC controller is used for PFC front stage control. This front stage works either in fixed frequency discontinues mode or critical conduction mode depends on the line and load conditions. Capacitors C_{42} , C_{30} , CY_1 , CY_2 with common mode choke L₉, inductors L₆, L_7 and varistor R_{28} form the EMI filter, which suppresses noise conducted to the mains. A bridge rectifier B_1 is used to rectify the input AC line voltage. Capacitor C5 filters the high frequency ripple current, which is generated by the PFC operation. In this application a classical PFC boost topology is used. The PFC power stage is formed by inductor L_2 , MOSFET switch Q₂, diode D₄, bulk capacitors C₆, C₇ and inrush current bypassing diode D₂. The current in the PFC stage is monitored by current sense network R₁₃, R₁₄ and R₁₅. Right input voltage operating range is adjusted by the Brown Out sensing network R₂, R₅, R₁₀, R₁₆, R₃₆ and C₂₁. Output voltage of the PFC stage is regulated to a nominal 395 Vdc via the feedback network R₃, R₆, R₁₁, R₂₂, R₂₉ and R_{30} . Sensing network described above is also used to monitor an overvoltage condition on the PFC output using the NCP1605 OVP pin. PFC regulation loop bandwidth is limited by the capacitor C22. The sensitivity of the zero current detection circuitry is given by the resistor R₃₉ value. Capacitor C_{19} and resistor R_{40} are used to control the maximum Q₂ switch on-time. Capacitor C₂₄ dictates the DCM operating frequency. Skip mode of the PFC front stage is initiated by the NCP1605 controller when the voltage on the STBY pin is lower than 0.3 V. Since the LLC stage voltage feedback and also bulk capacitor voltage have opposing reaction function (increasing when output load decreases), the divided (R35, R43 and C25) LLC stage primary current information has been used to trigger the PFC skip mode during light load conditions.

The controller receives the V_{CC} voltage from standby stage when standard operation mode is enabled by the TV set application.

Please refer to the application note AND8281/D for a detailed explanation on how to design a PFC front stage using the NCP1605 controller.

Standby Supply

An ON Semiconductor NCP1027 monolithic switcher (IC5) is used for auxiliary (or standby) power stage provide a cost effective solution, needed output power and low standby consumption, since this switcher offers skip mode capability under light load conditions. The nominal output power of this converter is 12.5 W. The unit is connected directly to the bulk capacitors so during standby conditions it operates from rectified mains. During normal operating conditions the switcher is energized by higher voltage (PFC front stage is working). After the start (that is assured by internal current supply) the switcher is powered from the auxiliary winding. Diode D_{23} is used for rectification and capacitor C_{47} to filter auxiliary voltage. Resistor R_{71} limits the I_{CC} current so the auto-recovery OVP is not activated for the correct V_{CC} voltage. The appropriate operating bulk

voltage range is restricted by the Brown Out sensing network R₆₄, R₆₈, R₇₀, R₇₇ and C₄₈. The NCP1027 switcher features adjustable ramp compensation capability - resistor R₇₈. Feedback loop is accomplished in the standard way: the output voltage level is regulated by the IC_6 to the value which is defined by resistors R₇₄ and R₈₀. Bias current for optcoupler OK₃ and regulator is provided from the standby supply output using resistors R72 and R73. Resistors R75 and R₇₉ are used to stabilize the maximum output power level with bulk voltage evaluation (CS comparator delay compensation). A standard RCD voltage clamp (R₆₆, R₆₇, C_{41} , D_{21}) is installed on the switcher drain to limit its voltage to safe level. There is an optional layout on the board so the TVS (D_{19}) can be used instead of the RCD clamp. This solution further decreases standby power consumption, however, price is slightly higher. Voltage from auxiliary winding, which is used to power the switcher is also used to feed up the PFC front stage and the main LLC converter control circuits. This voltage is limited by a simple zener regulator (D₂₂, Q₇, R₇₆ and C₄₆) and can be inhibited by the OK₂ action. Standby mode can be activated either by positive or negative logic signals (Q_5 or Q_6 assembled). Please refer to the application note AND8241/D for a detailed explanation on how to design a Standby flyback converter using the NCP1027 switcher.

LLC Power Stage

As previously mentioned, the NCP1396A (IC₃) resonant mode controller is used to control the main SMPS unit. The power stage of the LLC converter is formed by bulk capacitors C₆, C₇, MOSFETs Q₁, Q₃, transformer TR₁ and resonant capacitor C11. MOSFETs are driven directly by the controller. Resistors R₁₉ and R₂₀ damp the gate charging circuit to suppress overshoots on the gates and regulate EMI noise. Bootstrap diode D₁₄ is charging the bootstrap capacitor C₂₈ via resistor R₄₂. The bootstrap capacitor powers a floating driver when high side MOSFET is turned on. Safety resistors R₄ and R₁₂ are used to protect MOSFETs (during the experiments on the bench, for instance, when IC₃ is removed).

Center-tapped windings on 12 V and 24 V outputs increase the converter efficiency. A bridge rectifier is used for 30 V output. Different shottky diode types (D₃ with D₅, D_6 through D_{10} and D_{11}) are used for secondary rectification according to output voltage, power losses and also short circuit capability (not to damage diode during hard short on the output). The low ESR, high temperature electrolytic capacitors C_1 through C_4 , C8 through C_{10} , C_{12} through C_{16} , together with inductors L_1 , L_4 , and L_5 serve as filters for corresponding outputs. The secondary voltage regulator IC₂ regulates the output voltage to 24 V, which is value adjusted by resistor divider composed by R24, R48 and R49. If needed, there can be optionally used feedback from other secondary output(s) (R₂₆ and R₂₇ are included in the board layout). On the primary side, the optocoupler works in the connection with a common collector which also allows an easy implementation of the current regulation loop. Maximum current through the optocoupler transistor is adjusted by a resistor R_{33} . To speed up the regulation response, resistor R_{47} is connected to the feedback pin.

Capacitor C_{34} defines the soft start length. Note that the current regulation loop is used in this power stage so it takes control during the startup and affects the soft start action. Resistors R_{53} , R_{55} and R_{57} define maximum operating frequency, minimum operating frequency and dead time. The operation/fault time period during the overload is dictated by C_{35} and R_{54} values.

The LLC power stage operation is conditioned to the correct PFC front stage operation indicated by the PFC OK signal. This signal, divided down by resistors R_{32} and R_{56} , enables the NCP1396A controller when the bulk voltage is in the right range (PFC stage reached regulation).

Resistor divider R_{51} and R_{58} with bypass capacitor C_{37} are used to prepare skip mode during light or no load conditions on the power stage output. This skip mode limits the maximum needed operating frequency of the converter and improves no load efficiency of the LLC stage.

As already mentioned, the current feedback loop is used in this design. It limits the primary current of the power stage during overload and helps to implement hick-up mode. Primary current is sensed using charge pump R_{17} , C_{18} , D_{12} , D_{13} . Output of this charge pump is divided and filtered by R₃₁, R₁₈ and C₁₇. Maximum value of this voltage (and thus also the primary current) is regulated to 1.24 V by IC₄ regulator. The compensation of current regulation loop is accomplished by C_{31} capacitor. Zener diode D_{15} is used to lower maximum voltage on IC4. Since we need to bring up the NCP1396 feedback pin to increase the operating frequency during overload, transistor Q₄ with resistors R₃₈ and R₄₄ are used to perform inversion. Output voltage on the Q_4 collector is limited by zener diode D_{18} to 7.5 V maximally. This voltage divided down by resistors R52 and R59 triggers the slow fault input in case of an overload and also drives the NCP1396A feedback pin via diode D₁₇. This diode assures that the slow fault input is not triggered during light load conditions and in skip mode when the IC₃ feedback pin voltage is pushed up by the voltage feedback loop.

Controller IC₃ receives the V_{CC} voltage from standby stage during normal operation mode. Auxiliary winding of the resonant transformer W₇ (when half wave rectified by D₁) helps to power the control circuits when load on the standby supply output is too low and there is a lack of voltage on the standby auxiliary winding due to pure flyback transformer coupling. Please note that all outputs of the converter (including standby stage) are referenced to one secondary ground (S_GND).

LLC Transformer and Resonant Tank

A transformer from the standard production of the Pulse engineering company has been used for this design. This transformer, which is specially designed for LLC converters, offers extra high leakage inductance value thanks to a special windings arrangement (see demo board photo in Figure 24). The leakage inductance serves as a resonant inductance, which results in a cost effective solution since no additional inductor is needed to form a resonant tank. Specified parameters of the mentioned transformer are as follows:

Leakage (Resonant) Inductanc	$L_{s} = 115 \ \mu H$
Magnetizing Inductance	$L_{m} = 450 \ \mu H$
Primary Turns Count	38
24 V Output Turns Count	4
12 V Output Turns Count	2
30 V Output Turns Count	5
Auxiliary Winding Turns Count	3
Lm/Ls Ratio	450/115 = 3.9

Low value of the Lm/Ls ratio together with high turns ratio of the transformer will result in the high gain values.

Note that the manufacturer specifies the L_S inductance in a standard way - all secondary windings are shorted during the Ls measurements. This approach is OK for a transformer that has one secondary winding, but in our case we have three different secondary windings and two of them are center taped so only one of the corresponding winding participates on the resonance during one half of the switching period. As a result, the real leakage inductance that participates on the resonance is higher. Due to this fact, the simulation results of gain characteristics that are accomplished based on the transformer datasheet values, are not accurate enough to determine operating frequency range of the proposed converter.

The most accurate method how to obtain gain characteristics of the LLC converter that uses integrated transformer solution with multiple outputs, is to use a gain-phase analyzer. To do so it is necessary to load measured transformer outputs by equivalent AC resistances before measurements (first fundamental approximation - see [5] and [6]). For the center taped windings connect the AC resistance only to one of the windings of the pair - this will happen in reality - only one diode conducts the current during one half of the switching period. The AC resistance for corresponding output can be calculated using Equation 1.

$$R_{ac} = \frac{8}{\pi^2} \frac{V_{out} + V_f}{I_{out}}$$
 (eq. 1)

Where:

 V_{out} is the DC output voltage for given output

V_f is the rectifier forward voltage

I_{out} is the DC output current from given output

The output current has to be selected based on what type of gain characteristics one wants to obtain - full load, 10% load etc. Connection of the transformer during the gain characteristics measurements can be seen in Figure 2.



Figure 2. Transformer Connection During Gain Characteristics Measurements

The resonant tank quality factor of Q = 4.3 (that corresponds to resonant capacitor $C_r = 33$ nF) has been selected for this design in order to narrow operating frequency range of the converter.

The measured full load gain characteristic for the selected resonant tank components and 24 V output can be observed in Figure 3.

The gains that are needed to assure line regulation can be calculated using Equations 2 through 4:

$$G_{\min} = \frac{2(V_{out} + V_f)}{V_{inmax}} = \frac{2(24 + 0.6)}{425} = 0.116$$
 (eq. 2)

$$G_{nom} = \frac{2(V_{out} + V_f)}{V_{innom}} = \frac{2(24 + 0.6)}{395} = 0.125$$
 (eq. 3)

$$G_{max} = \frac{2(V_{out} + V_f)}{V_{inmax}} = \frac{2(24 + 0.6)}{350} = 0.141$$
 (eq. 4)

Theoretical series resonant frequency can also be calculated based on the Equation 5:

$$f_{r1} = \frac{1}{2 \cdot \pi \cdot \sqrt{L_r \cdot C_r}}$$

= $\frac{1}{2 \cdot 3.14 \cdot \sqrt{115 \cdot 10^{-6} \cdot 33 \cdot 10^{-9}}} = 81.7 \text{ kHz}$

Now, when looking back to the gain characteristic in Figure 3, the operating conditions of the full loaded LLC power stage can be read:

• The nominal operating frequency of such converter is 94.6 kHz (for nominal bulk voltage)

- The minimum needed operating frequency to assure low line regulation is 79 kHz
- The maximum needed operating frequency to assure high line regulation is 106 kHz
- The converter will operate in the calculated series resonant frequency for V_{bulk} = 360 VDC

As demonstrated, the converter will operate above the calculated theoretical series resonant frequency for nominal bulk voltage and full load. The ZCS capability is thus not achieved on the secondary diodes. Also the needed operating frequency range of this converter is very narrow, which is beneficial for LCD TV application - EMI radiation and filtering.

Gain characteristic of this converter for $I_{load} = 0.10 * I_{max}$ and same parameters as above is in Figure 4.



Figure 3. FLLC Converter Gain Characteristic for Full Load and Q = 4.3 (Cr = 33 nF)



This characteristic shows that the operating frequency has to be increased above 100 kHz to maintain regulation under light load conditions. Skip mode for the LLC stage can thus be easily implemented when maximum frequency is limited by F_{max} adjust resistor value.

Please refer to the application notes AND8255/D and AND8257/D for further information about the LLC converter resonant tank components design.

Results Summarization

Operating frequency of real LLC stage is 96.1 kHz for full load and $V_{bulk} = 395$ VDC, which is very close to the theoretical expectations. Output current level during which the skip mode takes place (LLC stage) has been set approximately to 8 W by R₅₀, R₅₇ divider. The PFC stage enters skip mode for output power lower than 25 W and leaves it for P_{out} > 30 W.

Measured efficiency for different input voltages and load conditions can be seen in Figures 5 and 6.



Standby (PFC and LLC disabled) consumption characteristic with line voltage for 0.5 W load on the standby output is in Figure 7. The consumption is below 1 W for any input voltage so today's energy agency's needs are easily met thanks to this design.



Figure 7. Standby Consumption versus Line Voltage - 0.5 W Load on STB Output



Figure 8. LLC Converter Waveforms During Skip Mode (1 - Bridge Voltage, 2 - Output Ripple on 12 V Output, 3 - Feedback Pin of the NCP1396)



Figure 10. LLC Stage Load Regulation for 230 V Input Voltage (2 - Output Voltage on the 24 V Output, 4 - Output Current from the 24 V Output)







Figure 9. Output Ripple on Each LLC Stage Output for Full Load Conditions (1 - 24 V Output, 2 - 30 V Output, 3 - 12 V Output)



Figure 11. LLC Stage Operating Under Short Circuit (1 - Ctimer Voltage, 2 - Feedback Voltage, 4 - Primary Current)













Layout Consideration

Leakage inductance on the primary side is not very critical for the LLC converter compared to other topologies, because it will only slightly modify the resonant frequency. However it is well to keep the areas of each power loop as small as possible due to radiated EMI noise. A two-sided PCB with one side ground plane helps (see Figures 21 and 23).

Thanks

I would like to thank the PULSE engineering company for provided samples and support for magnetic components used in this board.

I would also like to thank the COILCRAFT company for providing samples of the filtering inductors.

CAUTION

This demo board is intended for demonstration and evaluation purposes only and not for the end customer.

Literature

- 1. NCP1396A/B data sheet
- 2. NCP1605 data sheet
- 3. NCP1027 data sheet
- 4. Application note AND8241/D
- 5. Application note AND8255/D



Figure 15. Standby Power Supply Waveforms -Full Loaded (1 - NCP1027 Drain Voltage, 4 - Drain Current)



Figure 17. PFC Stage Skip Mode (1 - Q2 Drain Voltage, 2 - Bulk Voltage)

- 6. Application note AND8257/D
- 7. Application note AND8281/D
- 8. Bo Yang Topology Investigation for Front End DC-DC Power Conversion for Distributed Power System
- 9. M. B. Borage, S. R. Tiwari and S. Kotaiah -Design Optimization for an LCL - Type Series Resonant Converter
- 10. Pulse Engineering Transformer specification, No: 2652.0017A
- 11. Pulse Engineering Transformer specification, No: 2362.0031B
- 12. Pulse Engineering PFC inductor specification, No: 2702.0012A

Please contact Pulse Engineering Company regarding literature 10 - 12:

Pulse European Headquarters Einsteinstrasse 1 71083 Herrenberg Germany TEL: 49 7032 7806 0 FAX: 49 7032 7806 12





Figure 20. Component Placement on the Top Side (Top View)



Figure 21. Top Side (Top View)



Figure 22. Component Placement on the Bottom Side (Bottom View)



Figure 23. Bottom Side (Bottom View)



Figure 24. Photo of the Designed Prototype (Real Dimensions are 200 x 130 mm)

Designator	Qty	Description	Value	Toleranc e	Footprint	Manufacturer	Manufacturer Part Number
B1	1	Bridge Rectifier	KBU8M		KBU	Fairchild	KBU8M
C1, C2, C3, C8, C9, C12, C13, C14, C15, C43, C44	11	Electrolytic Capacitor	470μF/35V	20%	CPOL-EUE5-10.5	Rubycon	35ZL470M10X20
C10	1	Electrolytic Capacitor	220µF/63V	10%	CPOL-EUE5-10.5	Rubycon	63 YXA220M 10x16
C11	1	MKP Capacitor	33nF/630Vdc	20%	C-EU150-084X183	Arcotronics	R73-0.033 μF 15 630
C16	1	Electrolytic Capacitor	220µF/35V	20%	CPOL-EUE5-10.5	Rubycon	35 RX30220M 10x12.5
C17, C48	2	Ceramic Capacitor SMD	10n	10%	C-EUC1206	Epcos	B37872A5103K060
C18	1	Ceramic Capacitor	220p	10%	C-EU050-045X075	Panasonic	ECKA3A221KBP
C19	1	Ceramic Capacitor SMD	8n2	10%	C-EUC1206	Epcos	B37872A5822K060
C20, C23, C32, C33, C36, C52	6		NU		C-EUC1206		
C21	1	Ceramic Capacitor SMD	150n	10%	C-EUC1206	Epcos	B37872A5154K060
C22	1	Ceramic Capacitor SMD	220n	10%	C-EUC1206	Epcos	B37872A5224K060
C24	1	Ceramic Capacitor SMD	390p	5%	C-EUC1206	Epcos	B37871K5391J060
C25	1	Ceramic Capacitor SMD	1n2	10%	C-EUC1206	Epcos	B37872A5122K060
C26, C28, C38, C40, C51	5	Ceramic Capacitor SMD	100n	10%	C-EUC1206	Epcos	B37872A5104K060
C27	1	Ceramic Capacitor SMD	1n	10%	C-EUC1206	Epcos	B37872A5102K060
C29	1	Ceramic Capacitor SMD	22n	10%	C-EUC1206	Epcos	B37872A5223K060
C31	1	Ceramic Capacitor SMD	68n	10%	C-EUC1206	Epcos	B37872A5683K060
C34	1	Ceramic Capacitor SMD	1μF	10%	C-EUC1206	Epcos	B37872K0105K062
C35	1	Electrolytic Capacitor	4µ7/35V	20%	CPOL-EUE2-5	Rubycon	35 MH54.7M 4x5
C37	1	Ceramic Capacitor SMD	2n2	10%	CLEUC1206	Epcos	B37872A5222K060
C39	1		NU		C-EU150-064X183		
C4, C45	2	Electrolytic Capacitor	220μF/25V	20%	CPOL-EUE5-10.5	Rubycon	25 NXA220M 10x12.5
C41	1	MKP Capacitor	10nF/630Vdc	20%	C-EU075-032X103	Epcos	B32560J8103M000
C46	1	Electrolytic Capacitor	1u	20%	CPOL-EUE2-5	Rubycon	50 MH51M 4x5
C47	1	Electrolytic Capacitor	100uF/35V	20%	CPOL-EUE5.5-8	Rubycon	50 PK100M 8x11.5
C49	1	Electrolytic Capacitor	10μF/35V	20%	CPOL-EUE2.5-6	Rubycon	50 MH710M 6.3x7
C5, C30, C42	3	MKP Capacitor	1μF/275Vac	20%	C-EU225-108X268	Arcotronics	R46KM410000N1M
C50	1	Ceramic Capacitor SMD	100p	20%	C-EUC1206	Epcos	B37871K5101J060

NOTE: Please see the NCP1396A/B product folder on www.onsemi.com for PCB Gerber files and other collateral information regarding this demo board.

Designator	Qty	Description	Value	Toleranc e	Footprint	Manufacturer	Manufacturer Part Number
C6	1	Electrolytic Capacitor	100μF/450V	20%	EC18L40'22L35'	Rubycon	450 VXG100M 22x30
C7	1	Electrolytic Capacitor	100μF/450V	20%	EC18L40'22L35_90'	Rubycon	450 VXG100M 22x30
CY1, CY2, CY3	3	Ceramic Capacitor	2n2/Y1	20%	CYYC10B4	Murata	DE1E3KX222MA5B
D1, D8, D12, D13, D17	5	Diode	MMSD4148		SOD-123	ON Semiconductor	MMSD4148T1G
D11	1	Dual Diode	MBRF20100CT		TO-220	ON Semiconductor	MBRF20100CTG
D14, D21, D23	3	Diode	MURA160SMD		SMA	ON Semiconductor	MURA160T3G
D15	1	Zener Diode	3V3	5%	SOD-123	ON Semiconductor	MMSZ3V3T1G
D16	1		NU		SOD-123		
D18	1	Zener Diode	7V5	5%	SOD-123	ON Semiconductor	MMSZ7V5T1G
D19	1		NU		SMA		
D2	1	Diode	1N5408		Axial Lead 9.50x5.30mm	ON Semiconductor	1N5408G
D20	1	Diode	MBRS340T3		SMC	ON Semiconductor	MBRS320T3G
D22	1	Zener Diode	18V	5%	SOD-123	ON Semiconductor	MMSZ18T1G
D3, D5, D6, D7, D9, D10	6	Diode	MBRS4201T3G		SMC	ON Semiconductor	MBRS4201T3G
D4	1	Diode	MSR860		TO-220	ON Semiconductor	MSR860G
F1	1	FUSEHOLDER , 20X5MM	SH22, 5A		SH22, 5A	Multicomp	MCHTC-15M
	1	COVER, PCB FUSEHOLDER				Multicomp	MCHTC-150M
	1	FUSE, MEDIUM DELAY 4A	4A			BUSSMANN	TDC 210-4A
HEATSING_ 1	1	Heatsing	SK 454 150 SA		SK454/150_GND	Fischer Elektronik	SK 454 150 SA
HEATSING_ 2	1	Heatsing	SK 454 100 SA		SK454/100_GND	Fischer Elektronik	SK 454 100 SA
IC1	1	PFC Controller	NCP1605		SOIC 16	ON Semiconductor	NCP1605DR2G
IC2, IC6	2	Programmable Precision Reference	TL431SO8		SOIC-8	ON Semiconductor	NCV431AIDR2G
IC3	1	Resonant Controller	NCP1396A		SOIC 16	ON Semiconductor	NCP1396ADR2G
IC4	1	Programmable Precision Reference	TLV431A		SOT-23	ON Semiconductor	TLV431ASN1T1G
IC5	1	HV Switcher for Medium Power Offline SMPS	NCP1027		PDIP (8 Minus Pin 6)	ON Semiconductor	NCP1027P065G
J1, J3	2	Connector	22-23-2071		MOLEX-7PIN	Molex	22-23-2071
J2	1	Connector	22-23-2101		MOLEX-10PIN	Molex	22-23-2101
J4	1	Connector	22-23-2051		MOLEX-5PIN	Molex	22-23-2051
J5	1	Connector	LP7.5/2/903.2 OR		Weidmueller	Weidmueller	LP7.5/2/903.2 OR
L1, L4, L5, L10	4	Inductor	2μ2	20%	RFB0807	Coilcraft	RFB0807-2R2L
L2	1	Inductor	2702.0012A (260μH)	15%	Pulse_2702	Pulse	2702.0012A
L3	1		NU		2722.0005A		
L6, L7	2	Inductor	100µ	20%	DO5040H_100	Coilcraft	DO5040H-104MLB

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Designator	Qty	Description	Value	Toleranc e	Footprint	Manufacturer	Manufacturer Part Number
L8	1	-	NU		TLBI		
L9	1	EMI Filter	7mH	15%	TLBI	Pulse	6001.0069
OK1, OK2, OK3	3	Opto-Coupler	PC817		PC817SMD	Avago Technologies	HCPL-817-300E
Q1, Q3	2	MOSFET Transistor	STP12NM50FP		TO-220	STMicroelectronics	STP12NM50FP
Q2	1	MOSFET Transistor	STP20NM60FP		TO-220	STMicroelectronics	STP12NM50FP
Q4	1	PNP General Purpose Transistor	BC856-16LT1		SOT-23	ON Semiconductor	BC856-16LT1G
Q5, Q7	2	NPN General Purpose Transistor	BC817-16LT1		SOT-23	ON Semiconductor	BC817-16LT1G
Q6	1		NU		SOT-23		
R1, R8, R19, R20	4	Resistor SMD	10R	1%	R-EU_R1206	Vishay	RCA120610R0FKEA
R13	1	Resistor Trough Hole	0.1R	1%	R-EU_0617/22	Vishay	PAC300001007FAC000
R14	1	Resistor SMD	7k5	1%	R-EU_R1206	Vishay	RCA12067K50FKEA
R15, R51	2	Resistor SMD	8k2	1%	R-EU_M1206	Vishay	RCA12068K20FKEA
R17	1	Resistor SMD	47k	1%	R-EU_M1206	Vishay	RCA120647K0FKEA
R18	1	Resistor SMD	1k6	1%	R-EU_M1206	Vishay	RCA12061K60FKEA
R2, R5, R10, R16	4	Resistor SMD	1M8	1%	R-EU_M1206	Vishay	RCA12061M80FKEA
R21, R25, R26, R27, R37, R46, R50	7	Resistor SMD	NU	1%	R-EU_M1206	Vishay	
R22	1	Resistor SMD	1k1	1%	R-EU_M1206	Vishay	RCA12061K10FKEA
R23, R33, R34, R38, R41, R73	6	Resistor SMD	1k	1%	R-EU_M1206	Vishay	RCA12061K00FKEA
R24, R77	2	Resistor SMD	18k	1%	R-EU_M1206	Vishay	RCA120618K0FKEA
R28	1	Varistor	VDRH10S275TSE		VARISTOR10K300	Vishay	2381 584 T271S
R29	1	Resistor SMD	33k	1%	R-EU_M1206	Vishay	RCA120633K0FKEA
R3, R6, R11	3	Resistor SMD	1M3	1%	R-EU R1206	Vishay	RCA12061M30FKEA
R30	1	Resistor SMD	91k	1%	 R-EU_M1206	Vishay	RCA120691K0FKEA
R31, R48	2	Resistor SMD	3k3	1%	R-EU M1206	Vishay	RCA12063K30FKEA
R32, R39, R55	3	Resistor SMD	15k	1%	 R-EU_R1206	Vishay	RCA12061K50FKEA
R36	1	Resistor SMD	62k	1%	R-EU_M1206	Vishay	RCA120662K0FKEA
R4, R9, R12, R35, R43, R44, R52, R57, R61, R74, R79, R80	12	Resistor SMD	10k	1%	 R-EU_M1206	Vishay	RCA120610K0FKEA
R40	1	Resistor SMD	150R	1%	R-EU_R1206	Vishay	RCA1206150RFKEA
R42	1	Resistor SMD	18R	1%	R-EU_R1206	Vishay	RCA120618R0FKEA
R45	1	Resistor SMD	2k7	1%	 R-EU_M1206	Vishay	RCA12062K70FKEA
R47	1	Resistor SMD	2k2	1%	 R-EU_R1206	Vishay	RCA12062K20FKEA
R49	1	Resistor SMD	5k6	1%	 R-EU_M1206	Vishay	RCA12065K60FKEA
R53	1	Resistor SMD	24k	1%	R-EU R1206	Vishay	RCA120624K0FKEA

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Designator	Qty	Description	Value	Toleranc e	Footprint	Manufacturer	Manufacturer Part Number
R54	1	Resistor SMD	150k	1%	R-EU_R1206	Vishay	RCA1206150KFKEA
R56	1	Resistor SMD	6k8	1%	R-EU_R1206	Vishay	RCA12066K80FKEA
R58	1	Resistor SMD	1k5	1%	R-EU_R1206	Vishay	RCA12061K50FKEA
R59	1	Resistor SMD	6k2	1%	R-EU_R1206	Vishay	RCA12066K20FKEA
R60, R62, R63	3	Resistor SMD	820R	1%	R-EU_R1206	Vishay	RCA1206820RFKEA
R64, R68	2	Resistor SMD	1M2	1%	R-EU_R1206	Vishay	RCA12061M20FKEA
R65	1	Resistor SMD	4k7	1%	R-EU_R1206	Vishay	RCA12064K70FKEA
R66	1	Resistor Trough Hole	150k	1%	R-EU_0207/10	Vishay	MRS25000C1503FCT
R67	1	Resistor Trough Hole	47R	1%	R-EU_0207/10	Vishay	MRS25000C4709FCT
R69	1	Option for Thermistor	0R0		P594		
R7	1	Resistor SMD	0R0	1%	R-EU_M1206	Vishay	RCA12060000FKEA
R70	1	Resistor SMD	180k	1%	R-EU_M1206	Vishay	RCA1206180KFKEA
R71	1	Resistor SMD	3k9	1%	R-EU_M1206	Vishay	RCA12063K90FKEA
R72	1	Resistor SMD	100R	1%	R-EU_M1206	Vishay	RCA1206100RFKEA
R75	1	Resistor SMD	360k	1%	R-EU_M1206	Vishay	RCA1206360KFKEA
R76	1	Resistor SMD	470k	1%	R-EU_R1206	Vishay	RCA1206470KFKEA
R78	1	Resistor SMD	75k	1%	R-EU_M1206	Vishay	RCA120675K0FKEA
R81	1	Resistor Trough Hole, High Voltage	4M7	5%	R-EU_0414/15	Vishay	VR37000004704JA100
TR1	1	Resonant Transformer	2652.0017A	15%	2652	Pulse	2652.0017A
TR2	1	Standby Transformer	2362.0031B	15%	2362	Pulse	2362.0031B
B1	1	Bridge Rectifier	KBU8M		KBU	Fairchild	KBU8M
C1, C2, C3, C8, C9, C12, C13, C14, C15, C43, C44	11	Electrolytic Capacitor	470μF/35V	20%	CPOL-EUE5-10.5	Rubycon	35ZL470M10X20
C10	1	Electrolytic Capacitor	220μF/63V	10%	CPOL-EUE5-10.5	Rubycon	63 YXA220M 10x16
C11	1	MKP Capacitor	33nF/630Vdc	20%	C-EU150-084X183	Arcotronics	R73-0.033uF 15 630V
C16	1	Electrolytic Capacitor	220μF/35V	20%	CPOL-EUE5-10.5	Rubycon	35 RX30220M 10x12.5
C17, C48	2	Ceramic Capacitor SMD	10n	10%	C-EUC1206	Epcos	B37872A5103K060

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